



# (PLEASE FILL THIS IN AND Email it to websiteDU@du.ac.in and

cc: director@ducc.du.ac.in

Title Prof./Dr./Mr./Ms./ Mrs.	First	Name	SHYAMA	Last Na	ame	RATH		Photograph	
Designation	Prof	Professor							
Address	office: P-24, Pepartment of Physics and Astrophysics, Iniversity of Delhi, Delhi-110007					6.1			
Phone No Office	+91-	11- 2766	67155, 2766	67793					
Residence									
Mobile								and the second of the	
Email	srath	srath@physics.du.ac.in							
Web-Page	<u>http:</u>	//people	.du.ac.in/~si						
Educational Qualification	ons								
Degree		itution					Year		
Ph.D.		Indian Institute of Technology,						1994	
PG		Indian Institute of Technolo						1988	
UG Utkal University, Bhubaneswar Career Profile							1986		
University of Delhi		Profes	sor		Feb, 2 date	2011-	Те	Feaching and Research	
International Atomic Energy		Consu	ltant			2017- n, 2018	Co	onsultancy	
University of Delhi		Associ	ate Professo		Feb. 2 Feb, 2	2008- 2011	Те	aching and Research	
Chulalongkorn Univer Bangkok, Thailand	sity,	Visiting	g Faculty		Aug, 2 orese	2013- nt	Re	esearch	
University of Delhi		Reade			Feb, 2 Feb, 2	2005 to 2008	Те	aching and research	
I.I.T., Delhi		-	Scientist			002 to	Re	esearch project	
		Princip	al Investigat	tor I	Febru	ary 2005			
St. Stephens College,Delhi		Lecture	ər		Aug,0 Sept,(		Teaching (Undergraduate)		
Univ of Surrey,U.K.		Research Scientist			Nov,99 to July, 2002		Post-doctoral Research		
Imperial College, London, U.K.		Resea	rch Scientist		Jan,9 1999	9 to Nov,	Po	st-doctoral Research	
Univ. of Electro- communications,Tokyo		Resear	ch Scientist		April Sep, 1	96 to 1998	Po	st-doctoral Research	
I.I.T., Delhi		Project	t Scientist	]	May,9 Apr,9	95 to	Re	esearch project	

Administrative Assignments

Foreign Students' Advisor, University of Delhi

Member of various committees at the departmental and university, member of organizing committees of national and international conferences

Areas of Interest / Specialization

Broad Area: Experimental Condensed matter physics

(i) Fabrication and characterisation of semiconductor thin flms/heterostructures/nanostructures

- (ii) Optical spectroscopy (Raman, photoluminescence, and spectroscopic ellipsometry)
- (iii) Metal oxide semiconductors: synthesis, optical and electrical properties
- (iv) Ion beam modification of materials
- (v) Optical sensing with porous Si and semiconductor nanoparticles
- (vi) Photon correlation metrology and quantum optics

#### Subjects Taught

1. Atomic and Molecular Physics (M.Sc Final)

2. Quantum Mechanics (M.Sc Previous)

3. Nuclear and Particle Physics (M.Sc Final)

- 4. Lasers and Spectroscopy (M.Sc Final)
- 5. Experimental Solid State Physics (M.Sc Phys.)
- 6. Introductory Physics (M.Tech in Nanoscience and Nanotechnology)
- 7. Electromagnetic Theory (B.Sc)
- 8. Waves and Optics (BSc)
- 9. Waves and Optics Lab (M.Sc)
- 10. B.Sc Physics Lab (M.Sc)

**Research Guidance** 

List against each head (If applicable)

- 1. Supervision of awarded Doctoral Thesis: : 04
- 2. Ongoing;04

Publications Profile (last 5 years)

1. Determination of radiation hardness of silicon diodes E. Vittonea, J. Garcia Lopez, M. Jaksic, M.C. Jimenez Ramos, A. Lohstroh, Z. Pastuovic, S. Rath, R. Siegele, N. Skukan, G. Vizkelethy, A. Simon Nucl. Instr. & Meth. in Phys. Res. B, 449, pp6-10, <u>https://doi.org/10.1016/j.nimb.2019.04.032</u>

2. Growth mechanism and optical properties of Ge nanocrystals embedded in a GeOx matrix

K. Vijayarangamuthu, P. Kumar, M. Kumar and S. Rath, Applied Physics A, Vol. 124, pp. 712 https://doi.org/10.1007/s00339-018-2134-z, 2018

3. Optimization of the Concentration of Molybdenum Disulfide (MoS<sub>2</sub>) for Formation of Atomically Thin Layers, Vineeta and Shyama Rath, Springer Proceedings in Physics, Vol. 215, pp. 39-43 (2018)

4. High-yield synthesis and liquid-exfoliation of two-dimensional belt like hafnium disulphide" Harneet Kaur; Sandeep Yadav; Avanish Srivastava; Nidhi Singh; Shyama Rath; Jörg Schneider; Om Sinha; Ritu Srivastava, Nano Research, 343-353 https://doi.org/10.1007/s12274-017-1636-x (2018)

5. One-step synthesis of Au-coated porous silicon as a surface enhanced Raman scattering substrate for biomolecule detection, Vijayarangamuthu Kalimuthu, Shyama Rath, , Materials Letters, Volume 204, pp. 115–119 (2017) https://doi.org/10.1016/j.matlet.2017.06.030

6.Spectroscopic ellipsometry study of the free carrier absorption and bandgap of ZnO thin films: Effect of nonstoichiometry C. Singh, S.Nozaki, and Shyama Rath J. Appl. Phys. 118 (2015) DOI: 10.1063/1.4935629

7. UV photoluminescence from nanocrystalline tin oxide synthesized by a one-step hydrothermal method VijayarangamuthuKalimuthu Shyama Rath Materials Letters157(2015)11–14

8. Nanostructured tin oxide as a surface-enhanced- Raman-scattering substrate for detection of nitroaromatic compounds, K.Vijayarangamuthu and Shyama Rath, Int. J. Appl. Ceram. Technol., (2014) DOI:10.1111/ijac.12266

9. Nanoparticle size, oxidation state, and sensing response of tin oxide nanopowders using Raman spectroscopy K. Vijayarangamuthu and Shyama Rath, Journal of Alloys and Compounds 610, 706 (2014),

10. Effect of Thermal Annealing and Swift Heavy Ion Irradiation on the Optical Properties of Indium Oxide Thin Films, Neeti Tripathi, and Shyama Rath, ECS Journal of Solid State Science and Technology, 3 (3) P21-P25 (2014)

### Conference Organization/ Presentations (in the last three years)

Invited Talks:

- Micro-spectroscopic profiling of the layer-dependent optical properties of 2D materials, International Conference on Microscope and XXXIX Annual Meeting of Electron Microscope Society of India, Bhubaneswar July, 2018
- Spectroscopic characterization of wide bandgap oxide semiconductors, International Workshop on Advanced Materials and Device Technology November 22 - 24, 2017 (IWAMDT-2017) Anna University.Centre for International Affairs, Anna University, Chennai - 60002522-24 Nov., 2017
- Optoelectronic Device Parameters Of Wide Bandgap SemiconductorsDetermined By Spectroscopic Ellispometry, 9th International Conference on Materials for Advanced Technologies, Singapore, June 2017
- Simultaneous determination of the optical and electrical properties of ZnO films using spectroscopic ellipsometry International Conference on Technologically Advanced Materials (ICTAM) and Asian Meeting on Ferroelectricity (AMF10) November, 2016
- Optical Spectroscopy as a diagnostic tool for microelectronic materials and devices Faculty Development Programme on Advances in Microelectronics and Plasma Diagnostics Delhi Technological University and IEEE EDS Delhi Chapter2<sup>nd</sup> September, 2016
- Modulation of electronic and optical properties of 2D-semiconductors by ion beams"Ion Beam-Induced Spatio-temporal Structural Evolution of Matter: Towards New Quantum Technologies" from University of Torino, Italy International Atomic Energy Agency, Vienna23 -27 May 2016
- Optical probes for device parameters of ZnO films Symposium, "Thin Film Processing and Devices" International Conference on Advanced Electroaterials, Jeju, Korea, Nov 2015
- Higher Education and Social Enterprise" International seminar on "University Engagement" January 2015at Srinakharinwirot University, Thailand, January 2015
- Effect of argon pressure on the structural and optical properties of rf-sputtered ZnO thin films: Sojiphong Chatraphorn, Chaman Singh, Reena Goyal, Shyama Rath, Siam Physics Congress 2015 May 2015, Thailand
- Modelling and experimental investigations of irradiation effects in Si radiation detectors Siam Physics Congress 2015 May 2015, Thailand
- Resource Person: Seminar on Nanotechnology and Nanomaterial Overview, July, 2014, Asian Institute of Technology, Thailand.
- Session Chair: Symposium Thin Film Processing and Devices, ICAE 2015, Nov 2015, Jeju, Korea

#### **Conference Presentations:**

1. Effects of non-stoichiometry and Al-doping on the optical and electrical properties of ZnO thin films,

	s (Major Grants/Resear	· · · · ·		
Research Projects: S.No	Name of Agency	Title of project	Period of support	Completed/on- going
	International Atomic Energy Agency, Vienna	Utilization of Ion Accelerators for Studying and Modelling of Radiation Induced Defects in Semiconductors and Insulators	2011-2016	completed
	Defence Research Development Organisation, India	Synthesis & characterization of metal, metal- oxide, and polymeric substrates for detection of nitroaromatic	2010-2012	completed
3.	University Grants Commission,	compounds Nanocrystalline porous silicon for optical	2008-2011	completed
4.	India Inter-University Accelerator Centre, India	biosensing Swift heavy ion modification of In2O3 films	2008-2011	completed
5.	Univ. of Delhi, R & D Grant,	Nanomaterials Research and Optical Metrology	2007-13	ongoing
wards and Disti	nctions			
1. University Po 2. National Sch 3. Qualified JRI 4. Graduate Ap 5. Monbusho Fo	sition in Physics Honou olarship by Ministry of I F CSIR Fellowship 198 titude Test in Engineer ellowship by Governme y, U.K Dept. of Science	Human Resource and 8 ing (GATE) Fellowsh ent of Japan in 1996	d Development, durii p in 1988	ng Masters' course

SIAM Physics Congress held in March 2014 in Thailand

1.Reviewer: American Institute of Physics, Institute of Physics, U.K., Elsevier, Springer. Taylor & Francis Journals,, Japanese Journal of Applied Physics,

- 2. Review Committee Member of NCERT Physics textbook for Class 12.
- 3. Review Committee Member of NCERT Physics textbook Exemplar Problems in Physics for Class 11.
  - 4 Memberships

American Vacuum Society Materials Research Society, India (Life Member) Indian Laser Association (Life member)

## Other Activities

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Signature of Faculty Member

 You are also requested to also give your complete resume as a DOC or PDF file to be attached as a link on your faculty page.